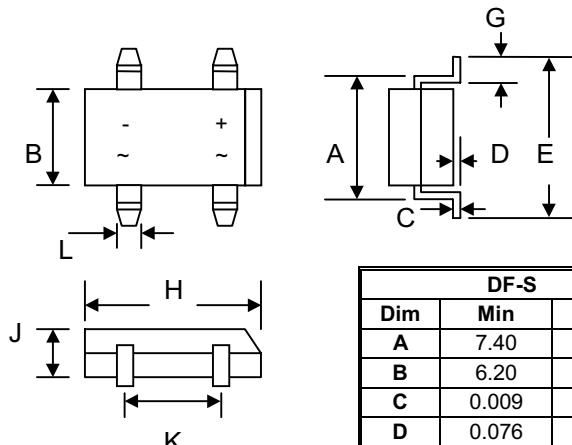


Features

- Glass Passivated Die Construction
- Low Forward Voltage Drop
- High Current Capability
- High Surge Current Capability
- Designed for Surface Mount Application
- Plastic Material – UL Recognition Flammability Classification 94V-O



Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: As Marked on Case
- Weight: 0.38 grams (approx.)
- Mounting Position: Any
- Marking: Type Number

*Low profile models (J = 2.20~2.50mm) are available.
Please consult factory.

| DF-S | | |
|------|-------|-------|
| Dim | Min | Max |
| A | 7.40 | 7.90 |
| B | 6.20 | 6.50 |
| C | 0.009 | 0.25 |
| D | 0.076 | 0.33 |
| E | — | 10.40 |
| G | 1.02 | 1.53 |
| H | 8.13 | 8.51 |
| J* | 3.20 | 3.40 |
| K | 5.0 | 5.20 |
| L | 1.00 | 1.20 |

All Dimensions in mm

Maximum Ratings and Electrical Characteristics $\text{@T}_A=25^\circ\text{C}$ unless otherwise specified

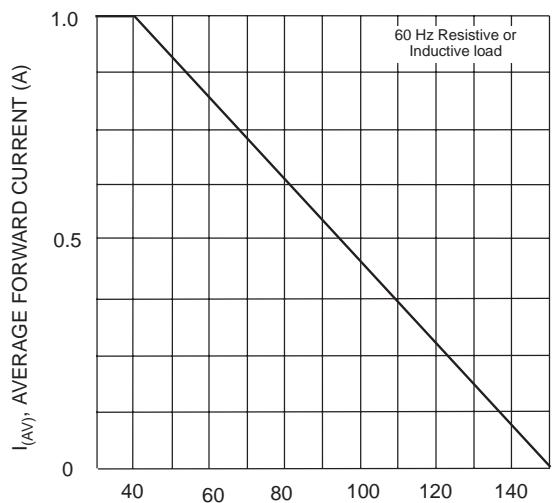
Single Phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

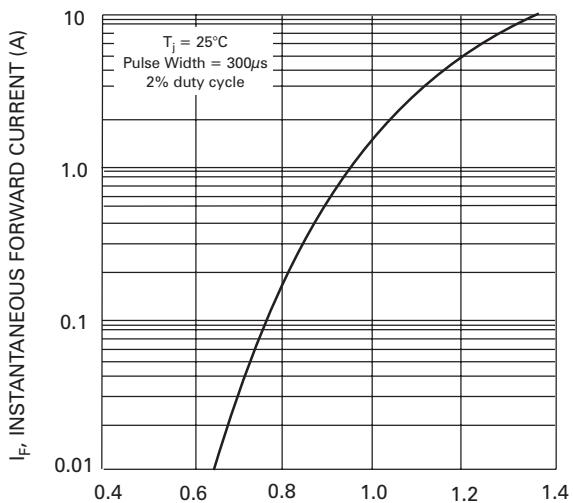
| Characteristic | Symbol | DF 005S | DF 01S | DF 02S | DF 04S | DF 06S | DF 08S | DF 10S | Unit |
|---|-----------------------------------|------------|-----------|-----------|-----------|-------------|-----------|-----------|------------------|
| Peak Repetitive Reverse Voltage | V _{RRM} | | | | | | | | |
| Working Peak Reverse Voltage | V _{RWM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| DC Blocking Voltage | V _R | | | | | | | | |
| RMS Reverse Voltage | V _{R(RMS)} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Average Rectified Output Current $\text{@T}_A = 40^\circ\text{C}$ | I _O | | | | | 1.0 | | | A |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method) | I _{FSM} | | | | | 30 | | | A |
| Forward Voltage per element $\text{@I}_F = 1.0\text{A}$ | V _F | | | | | 1.1 | | | V |
| Peak Reverse Current $\text{@T}_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage $\text{@T}_A = 125^\circ\text{C}$ | I _{RM} | | | | | 10 | | | μA |
| Typical Junction Capacitance per element (Note 1) | C _J | | | | | 25 | | | pF |
| Typical Thermal Resistance (Note 2) | R _{θJA} | | | | | 110 | | | K/W |
| Operating and Storage Temperature Range | T _j , T _{STG} | | | | | -65 to +150 | | | $^\circ\text{C}$ |

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

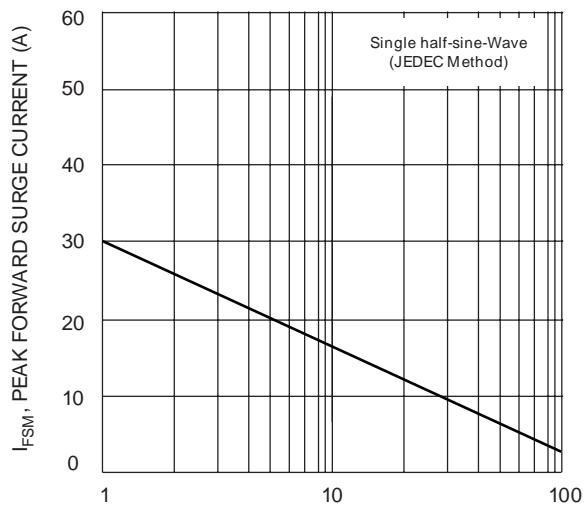
2. Thermal resistance junction to ambient mounted on PC board with 5.0mm² (0.03mm thick) land areas.



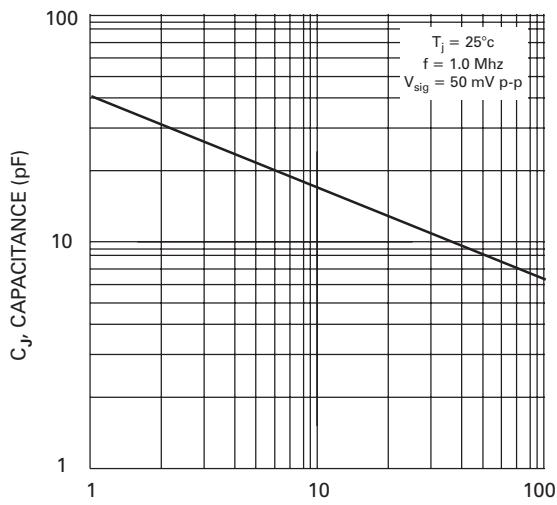
T_A , AMBIENT TEMPERATURE (°C)
Fig. 1 Output Current Derating Curve



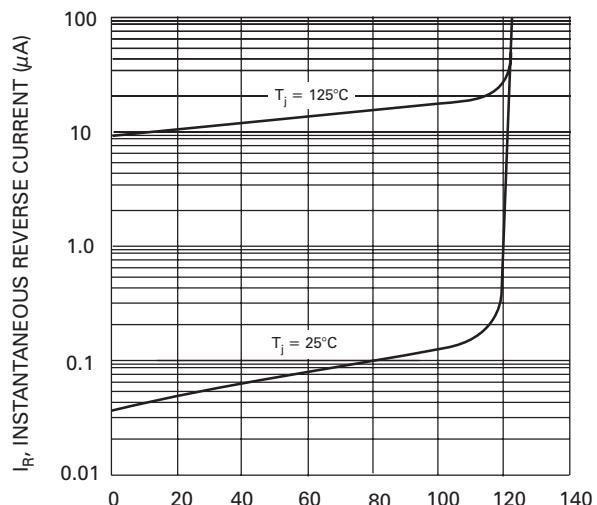
V_F , INSTANTANEOUS FORWARD VOLTAGE (V)
Fig. 2 Typ Forward Characteristics (per element)



NUMBER OF CYCLES AT 60 Hz
Fig. 3 Max Non-Repetitive Peak Forward Surge Current



V_R , REVERSE VOLTAGE (V)
Fig. 4 Typ Junction Capacitance (per element)



PERCENT OF RATED PEAK REVERSE VOLTAGE (%)
Fig. 5 Typ Reverse Characteristics (per element)